

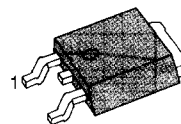
D-PACK FOR SURFACE MOUNT**APPLICATIONS**

- High DC Current Gain
- Built-in a Damper Diode at E-C
- Lead Formed for Surface Mount Applications (No Suffix)
- Straight Lead (I. PACK, " - I " Suffix)
- Electrically Similar to Popular TIP127

ABSOLUTE MAXIMUM RATINGS

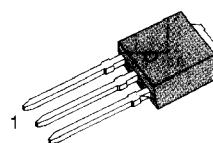
Characteristic	Symbol	Rating	Unit
Collector Base Voltage	V_{CBO}	- 100	V
Collector Emitter Voltage	V_{CEO}	- 100	V
Emitter Base Voltage	V_{EBO}	- 5	V
Collector Current (DC)	I_C	- 8	A
Collector Current (Pulse)	I_C	- 16	A
Base Current	I_B	- 120	mA
Collector Dissipation ($T_C=25^\circ\text{C}$)	P_C	20	W
Collector Dissipation ($T_A=25^\circ\text{C}$)	P_C	1.75	W
Junction Temperature	T_J	150	$^\circ\text{C}$
Storage Temperature	T_{STG}	-65 ~ 150	$^\circ\text{C}$

D-PAK



1. Base 2. Collector 3. Emitter

I-PAK



1. Base 2. Collector 3. Emitter

ELECTRICAL CHARACTERISTICS ($T_C=25^\circ\text{C}$)

Characteristic	Symbol	Test Conditions	Min	Max	Unit
* Collector Emitter Sustaining Voltage	$V_{CEO(sus)}$	$I_C = -30\text{mA}, I_B = 0$	- 100		V
Collector Cutoff Current	I_{CEO}	$V_{CE} = -50\text{V}, I_B = 0$		- 10	μA
Collector Cutoff Current	I_{CBO}	$V_{CB} = -100\text{V}, I_E = 0$		- 10	μA
Emitter Cutoff Current	I_{EBO}	$V_{EB} = -5\text{V}, I_C = 0$		- 2	mA
* DC Current Gain	h_{FE}	$V_{CE} = -4\text{V}, I_C = -4\text{A}$ $V_{CE} = -4\text{V}, V_{EB} = -8\text{A}$	1000 100	12K	
* Collector Emitter Saturation Voltage	$V_{CE(sat)}$	$I_C = -4\text{A}, I_B = -16\text{mA}$ $I_C = -8\text{A}, I_B = -80\text{mA}$		- 2 - 4	V V
* Base Emitter Saturation Voltage	$V_{BE(sat)}$	$I_C = -8\text{A}, I_B = -80\text{mA}$		- 4.5	V
* Base Emitter On Voltage	$V_{BE(on)}$	$V_{CE} = -4\text{V}, I_C = -4\text{A}$		- 2.8	V
Output Capacitance	C_{OB}	$V_{CB} = -10\text{V}, I_E = 0$ $f = 0.1\text{MHz}$		200	pF

* Pulse Test: $PW \leq 300\mu\text{s}$, Duty Cycles $\leq 2\%$